Charge Transport in Disordered Solids with Applications in Electronics

Edited by

Sergei Baranovski
Philipps University Marburg, Germany

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Charge Transport in Disordered Solids with Applications in Electronics

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Library of Congress Cataloging-in-Publication Data

Charge transport in disordered solids with applications in electronics / edited by Sergei Baranovski.
p. cm. – (Wiley series in materials for electronic and optoelectronic applications)
Includes bibliographical references and index.
ISBN-13: 978-0-470-09504-1 (cloth : alk. paper)
ISBN-10: 0-470-09504-0 (cloth : alk. paper)
1. Amorphous semiconductors–Electric properties. 2. Solids–Electric properties.
3. Semiconductros–Materials. I. Baranovski, Sergei. II. Series.
TK7871.99.A45C53 2006
621.3815′2–dc22

2006014686

British Library Cataloguing in Publication Data

A catalogue record for this book is available from the British Library

ISBN-13 978-0-470-09504-1 (HB)
ISBN-10 0-470-09504-0 (HB)

Typeset in 10/12 pt Times by SNP Best-set Typesetter Ltd., Hong Kong
Printed and bound in Great Britain by Antony Rowe, Chippenham, Wiltshire
This book is printed on acid-free paper responsibly manufactured from sustainable forestry in which at least two trees are planted for each one used for paper production.

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Series Preface

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